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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	2 Core, 32-Bit
Speed	852MHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, DDR3L, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	HDMI, Keypad, LCD, LVDS, MIPI/DSI, Parallel
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (3), USB 2.0 OTG + PHY (1)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 125°C (TJ)
Security Features	ARM TZ, A-HAB, CAAM, CSU, SJC, SNVS
Package / Case	624-FBGA, FCBGA
Supplier Device Package	624-FCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6dp4avt8aa

- USB:
  - One High Speed (HS) USB 2.0 OTG (Up to 480 Mbps), with integrated HS USB PHY
  - Three USB 2.0 (480 Mbps) hosts:
    - One HS host with integrated High Speed PHY
    - Two HS hosts with integrated HS-IC USB (High Speed Inter-Chip USB) PHY
- Expansion PCI Express port (PCIe) v2.0 one lane
  - PCI Express (Gen 2.0) dual mode complex, supporting Root complex operations and Endpoint operations. Uses x1 PHY configuration.
- Miscellaneous IPs and interfaces:
  - SSI block capable of supporting audio sample frequencies up to 192 kHz stereo inputs and outputs with I^2S mode
  - ESAI is capable of supporting audio sample frequencies up to 260kHz in I2S mode with 7.1 multi channel outputs
  - Five UARTs, up to 5.0 Mbps each:
    - Providing RS232 interface
    - Supporting 9-bit RS485 multidrop mode
    - One of the five UARTs (UART1) supports 8-wire while others four supports 4-wire. This is due to the SoC IOMUX limitation, since all UART IPs are identical.
  - Five eCSPI (Enhanced CSPI)
  - Three I2C, supporting 400 kbps
  - Gigabit Ethernet Controller (IEEE1588 compliant), 10/100/1000[1] Mbps
  - Four Pulse Width Modulators (PWM)
  - System JTAG Controller (SJC)
  - GPIO with interrupt capabilities
  - 8x8 Key Pad Port (KPP)
  - Sony Philips Digital Interconnect Format (SPDIF), Rx and Tx
  - Two Controller Area Network (FlexCAN), 1 Mbps each
  - Two Watchdog timers (WDOG)
  - Audio MUX (AUDMUX)
  - MLB (MediaLB) provides interface to MOST Networks (150 Mbps) with the option of DTCP cipher accelerator

The i.MX 6DualPlus/6QuadPlus processors integrate advanced power management unit and controllers:

- Provide PMU, including LDO supplies, for on-chip resources
- Use Temperature Sensor for monitoring the die temperature
- Support DVFS techniques for low power modes
- Use Software State Retention and Power Gating for ARM and MPE

1. The theoretical maximum performance of 1 Gbps ENET is limited to 470 Mbps (total for Tx and Rx) due to internal bus throughput limitations. The actual measured performance in optimized environment is up to 400 Mbps. For details, see the ERR004512 erratum in the i.MX 6Dual/6Quad errata document (IMX6DQCE).

[10] All digital I/O supplies (NVCC_xxxx) must be powered under normal conditions whether the associated I/O pins are in use or not, and associated I/O pins need to have a pull-up or pull-down resistor applied to limit any floating gate current.

[11] This supply also powers the pre-drivers of the DDR I/O pins; therefore, it must always be provided, even when LVDS is not used.

4.1.4 External Clock Sources

Each i.MX 6DualPlus/6QuadPlus processor has two external input system clocks: a low frequency (RTC_XTALI) and a high frequency (XTALI).

The RTC_XTALI is used for low-frequency functions. It supplies the clock for wake-up circuit, power-down real time clock operation, and slow system and watchdog counters. The clock input can be connected to either an external oscillator or a crystal using the internal oscillator amplifier. Additionally, there is an internal ring oscillator, that can be used instead of RTC_XTALI when accuracy is not important.

The system clock input XTALI is used to generate the main system clock. It supplies the PLLs and other peripherals. The system clock input can be connected to either an external oscillator or a crystal using the internal oscillator amplifier.

NOTE

The internal RTC oscillator does not provide an accurate frequency and is affected by process, voltage and temperature variations. Freescale strongly recommends using an external crystal as the RTC_XTALI reference. If the internal oscillator is used instead, careful consideration should be given to the timing implications on all of the SoC modules dependent on this clock.

Table 7 shows the interface frequency requirements.

Table 7. External Input Clock Frequency

Parameter Description	Symbol	Min	Typ	Max	Unit
RTC_XTALI Oscillator[1,2]	f_{ckil}	—	32.768[3]/32.0	—	kHz
XTALI Oscillator[4,2]	f_{xtal}	—	24	—	MHz

[1] External oscillator or a crystal with internal oscillator amplifier.

[2] The required frequency stability of this clock source is application dependent. For recommendations, see the Hardware Development Guide for i.MX 6Dual, 6Quad, 6Solo, 6DualLite Families of Applications Processors (IMX6DQ6SDLHDG).

[3] Recommended nominal frequency 32.768 kHz.

[4] External oscillator or a fundamental frequency crystal with internal oscillator amplifier.

The typical values shown in Table 7 are required for use with Freescale BSPs to ensure precise time keeping and USB operation. For RTC_XTALI operation, two clock sources are available:

- On-chip 40 kHz ring oscillator: This clock source has the following characteristics:
  - Approximately 25 µA more Idd than crystal oscillator
  - Approximately ±50% tolerance
  - No external component required
  - Starts up quicker than 32 kHz crystal oscillator
- External crystal oscillator with on-chip support circuit

Table 8. Maximum Supply Currents

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
i.MX 6QuadPlus: VDD_ARM_IN + VDD_ARM23_IN	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 125°C	3920	2500	mA
	• ARM frequency = 852 MHz • ARM LDOs set to 1.3V • T_j = 125°C	3630	2260	mA
i.MX 6DualPlus: VDD_ARM_IN[1]	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 125°C	2350	1200	mA
	• ARM frequency = 852 MHz • ARM LDOs set to 1.3V • T_j = 125°C	2110	1090	mA
i.MX 6DualPlus: or i.MX 6Quad: VDD_SOC_IN	• Running 3DMark • GPU frequency = 720 MHz • SOC LDO set to 1.3V • T_j = 125°C	3900		mA
VDD_HIGH_IN	—	125[2]		mA
VDD_SNVS_IN	—	275[3]		µA
USB_OTG_VBUS/ USB_H1_VBUS (LDO 3P0)	—	25[4]		mA
Primary Interface (IO) Supplies				
NVCC_DRAM	—	(see note[5])		
NVCC_ENET	N=10	Use maximum IO equation[6]		
NVCC_LCD	N=29	Use maximum IO equation[6]		
NVCC_GPIO	N=24	Use maximum IO equation[6]		
NVCC_CSI	N=20	Use maximum IO equation[6]		
NVCC_EIM0	N=19	Use maximum IO equation[6]		
NVCC_EIM1	N=14	Use maximum IO equation[6]		
NVCC_EIM2	N=20	Use maximum IO equation[6]		
NVCC_JTAG	N=6	Use maximum IO equation[6]		
NVCC_RGMII	N=6	Use maximum IO equation[6]		
NVCC_SD1	N=6	Use maximum IO equation[6]		
NVCC_SD2	N=6	Use maximum IO equation[6]		
NVCC_SD3	N=11	Use maximum IO equation[6]		
NVCC_NANDF	N=26	Use maximum IO equation[6]		
NVCC_MIPI	—	25.5		mA

Table 8. Maximum Supply Currents (continued)

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
NVCC_LVDS2P5	—	NVCC_LVDS2P5 is connected to VDD_HIGH_CAP at the board level. VDD_HIGH_CAP is capable of handing the current required by NVCC_LVDS2P5.		
MISC				
DRAM_VREF	—	1		mA

1 i.MX 6DualPlus numbers assume VDD_ARM23_IN and VDD_ARM23_CAP are connected to ground.

2 The actual maximum current drawn from VDD_HIGH_IN will be as shown plus any additional current drawn from the VDD_HIGH_CAP outputs, depending upon actual application configuration (for example, NVCC_LVDS_2P5, NVCC_MIPI, or HDMI, PCIe, and SATA VPH supplies).

3 Under normal operating conditions, the maximum current on VDD_SNVS_IN is shown Table 8. The maximum VDD_SNVS_IN current may be higher depending on specific operating configurations, such as BOOT_MODE[1:0] not equal to 00, or use of the Tamper feature. During initial power on, VDD_SNVS_IN can draw up to 1 mA if the supply is capable of sourcing that current. If less than 1 mA is available, the VDD_SNVS_CAP charge time will increase.

4 This is the maximum current per active USB physical interface.

5 The DRAM power consumption is dependent on several factors such as external signal termination. DRAM power calculators are typically available from memory vendors which take into account factors such as signal termination.
See the *i.MX 6Dual/6Quad Power Consumption Measurement Application Note* (AN4509) for examples of DRAM power consumption during specific use case scenarios.

6 General equation for estimated, maximum power consumption of an IO power supply:
Imax = N x C x V x (0.5 x F)
Where:
N—Number of IO pins supplied by the power line
C—Equivalent external capacitive load
V—IO voltage
(0.5 xF)—Data change rate. Up to 0.5 of the clock rate (F)
In this equation, Imax is in Amps, C in Farads, V in Volts, and F in Hertz.

4.1.6 Low Power Mode Supply Currents

Table 9 shows the current core consumption (not including I/O) of the i.MX 6DualPlus/6QuadPlus processors in selected low power modes.

Table 9. Stop Mode Current and Power Consumption

Mode	Test Conditions	Supply	Typical[1]	Unit
WAIT	• ARM, SoC, and PU LDOs are set to 1.225 V • HIGH LDO set to 2.5 V • Clocks are gated • DDR is in self refresh • PLLs are active in bypass (24 MHz) • Supply voltages remain ON	VDD_ARM_IN (1.4 V)	6	mA
		VDD_SOC_IN (1.4 V)	23	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	52	mW

Table 9. Stop Mode Current and Power Consumption (continued)

Mode	Test Conditions	Supply	Typical[1]	Unit
STOP_ON	• ARM LDO set to 0.9 V • SoC and PU LDOs set to 1.225 V • HIGH LDO set to 2.5 V • PLLs disabled • DDR is in self refresh	VDD_ARM_IN (1.4 V)	7.5	mA
		VDD_SOC_IN (1.4 V)	22	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	52	mW
STOP_OFF	• ARM LDO set to 0.9 V • SoC LDO set to 1.225 V • PU LDO is power gated • HIGH LDO set to 2.5 V • PLLs disabled • DDR is in self refresh	VDD_ARM_IN (1.4 V)	7.5	mA
		VDD_SOC_IN (1.4 V)	13.5	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	41	mW
STANDBY	• ARM and PU LDOs are power gated • SoC LDO is in bypass • HIGH LDO is set to 2.5 V • PLLs are disabled • Low voltage • Well Bias ON • Crystal oscillator is enabled	VDD_ARM_IN (0.9 V)	0.1	mA
		VDD_SOC_IN (1.05 V)	13	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	22	mW
Deep Sleep Mode (DSM)	• ARM and PU LDOs are power gated • SoC LDO is in bypass • HIGH LDO is set to 2.5 V • PLLs are disabled • Low voltage • Well Bias ON • Crystal oscillator and bandgap are disabled	VDD_ARM_IN (0.9 V)	0.1	mA
		VDD_SOC_IN (1.05 V)	2	mA
		VDD_HIGH_IN (3.0 V)	0.5	mA
		Total	3.4	mW
SNVS Only	• VDD_SNVS_IN powered • All other supplies off • SRTC running	VDD_SNVS_IN (2.8V)	41	µA
		Total	115	µW

[1] The typical values shown here are for information only and are not guaranteed. These values are average values measured on a worst-case wafer at 25°C.

4.6.1 XTALI and RTC_XTALI (Clock Inputs) DC Parameters

Table 21 shows the DC parameters for the clock inputs.

Table 21. XTALI and RTC_XTALI DC Parameters

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
XTALI high-level DC input voltage	Vih	—	0.8 x NVCC_PLL_OUT	—	NVCC_PLL_ OUT	V
XTALI low-level DC input voltage	Vil	—	0	—	0.2	V
RTC_XTALI high-level DC input voltage	Vih	—	0.8	—	1.1	V
RTC_XTALI low-level DC input voltage	Vil	—	0	—	0.2	V
Input capacitance	C_{IN}	Simulated data	—	5	—	pF
Startup current	$I_{XTALI\_STARTUP}$	Power-on startup for 0.15msec with a driven 32KHz RTC clock @ 1.1V. This current draw is present even if an external clock source directly drives XTALI	—	—	600	uA
DC input current	I_{XTALI_DC}	—	—	—	2.5	uA

4.6.2 General Purpose I/O (GPIO) DC Parameters

Table 22 shows DC parameters for GPIO pads. The parameters in Table 22 are guaranteed per the operating ranges in Table 6, unless otherwise noted.

Table 22. GPIO I/O DC Parameters

Parameter	Symbol	Test Conditions	Min	Max	Unit
High-level output voltage[1]	Voh	Ioh = -0.1 mA (DSE[2] = 001, 010) Ioh = -1 mA (DSE = 011, 100, 101, 110, 111)	OVDD – 0.15	—	V
Low-level output voltage[1]	Vol	Iol = 0.1 mA (DSE[2] = 001, 010) Iol = 1mA (DSE = 011, 100, 101, 110, 111)	—	0.15	V
High-Level DC input voltage[1, 3]	Vih	—	0.7 × OVDD	OVDD	V
Low-Level DC input voltage[1, 3]	Vil	—	0	0.3 × OVDD	V
Input Hysteresis	Vhys	OVDD = 1.8 V OVDD = 3.3 V	0.25	—	V
Schmitt trigger VT+[3, 4]	VT+	—	0.5 × OVDD	—	V
Schmitt trigger VT–[3, 4]	VT–	—	—	0.5 × OVDD	V
Input current (no pull-up/down)	Iin	Vin = OVDD or 0	-1	1	µA
Input current (22 kΩ pull-up)	Iin	Vin = 0 V Vin = OVDD	—	212 1	µA

Table 23. LPDDR2 I/O DC Electrical Parameters[1] (continued)

Parameters	Symbol	Test Conditions	Min	Max	Unit
240 Ω unit calibration resolution	Rres	—	—	10	Ω
Keeper circuit resistance	Rkeep	—	110	175	kΩ

1 Note that the JEDEC LPDDR2 specification (JESD209_2B) supersedes any specification in this document.

2 The single-ended signals need to be within the respective limits (Vih(dc) max, Vil(dc) min) for single-ended signals as well as the limitations for overshoot and undershoot (see Table 29).

4.6.3.2 DDR3/DDR3L Mode I/O DC Parameters

The DDR3/DDR3L interface mode fully complies with JESD79-3D DDR3 JEDEC standard release April, 2008. The parameters in Table 24 are guaranteed per the operating ranges in Table 6, unless otherwise noted.

Table 24. DDR3/DDR3L I/O DC Electrical Parameters

Parameters	Symbol	Test Conditions	Min	Max	Unit
High-level output voltage	Voh	Ioh = -0.1 mA Voh (DSE = 001)	0.8 × OVDD[1]	—	V
		Ioh = -1 mA Voh (for all except DSE = 001)			
Low-level output voltage	Vol	Iol = 0.1 mA Vol (DSE = 001)	—	0.2 × OVDD	V
		Iol = 1 mA Vol (for all except DSE = 001)			
Input reference voltage	Vref[2]	—	0.49 × OVDD	0.51 × OVDD	
DC input Logic High	Vih(dc)	—	Vref+0.1	OVDD	V
DC input Logic Low	Vil(dc)	—	OVSS	Vref-0.1	V
Differential input Logic High	Vih(diff)	—	0.2	See Note[3]	V
Differential input Logic Low	Vil(diff)	—	See Note[3]	-0.2	V
Termination Voltage	Vtt	Vtt tracking OVDD/2	0.49 × OVDD	0.51 × OVDD	V
Input current (no pull-up/down)	Iin	Vin = 0 or OVDD	-2.9	2.9	μA
Pull-up/pull-down impedance mismatch	MMpupd	—	-10	10	%
240 Ω unit calibration resolution	Rres	—	—	10	Ω
Keeper circuit resistance	Rkeep	—	105	175	kΩ

1 OVDD – I/O power supply (1.425 V–1.575 V for DDR3 and 1.283 V–1.45 V for DDR3L).

2 Vref – DDR3/DDR3L external reference voltage.

3 The single-ended signals need to be within the respective limits (Vih(dc) max, Vil(dc) min) for single-ended signals as well as the limitations for overshoot and undershoot (see Table 30).

4.7.1 General Purpose I/O AC Parameters

The I/O AC parameters for GPIO in slow and fast modes are presented in the Table 27 and Table 28, respectively. Note that the fast or slow I/O behavior is determined by the appropriate control bits in the IOMUXC control registers.

Table 27. General Purpose I/O AC Parameters 1.8 V Mode

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Pad Transition Times, rise/fall (Max Drive, ipp_dse=111)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	2.72/2.79 1.51/1.54	ns
Output Pad Transition Times, rise/fall (High Drive, ipp_dse=101)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	3.20/3.36 1.96/2.07	
Output Pad Transition Times, rise/fall (Medium Drive, ipp_dse=100)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	3.64/3.88 2.27/2.53	
Output Pad Transition Times, rise/fall (Low Drive. ipp_dse=011)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	4.32/4.50 3.16/3.17	
Input Transition Times[1]	trm	—	—	—	25	ns

1 Hysteresis mode is recommended for inputs with transition times greater than 25 ns.

Table 28. General Purpose I/O AC Parameters 3.3 V Mode

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Pad Transition Times, rise/fall (Max Drive, ipp_dse=101)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	1.70/1.79 1.06/1.15	ns
Output Pad Transition Times, rise/fall (High Drive, ipp_dse=011)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	2.35/2.43 1.74/1.77	
Output Pad Transition Times, rise/fall (Medium Drive, ipp_dse=010)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	3.13/3.29 2.46/2.60	
Output Pad Transition Times, rise/fall (Low Drive. ipp_dse=001)	tr, tf	15 pF Cload, slow slew rate 15 pF Cload, fast slew rate	—	—	5.14/5.57 4.77/5.15	
Input Transition Times[1]	trm	—	—	—	25	ns

1 Hysteresis mode is recommended for inputs with transition times greater than 25 ns.

Table 40. EIM Bus Timing Parameters (continued)

ID	Parameter	Min[1]	Max[1]	Unit
WE4	Clock rise to address valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE5	Clock rise to address invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE6	Clock rise to EIM_CSx_B valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE7	Clock rise to EIM_CSx_B invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE8	Clock rise to EIM_WE_B valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE9	Clock rise to EIM_WE_B invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE10	Clock rise to EIM_OE_B valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE11	Clock rise to EIM_OE_B invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE12	Clock rise to EIM_EBx_B valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE13	Clock rise to EIM_EBx_B invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE14	Clock rise to EIM_LBA_B valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE15	Clock rise to EIM_LBA_B invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE16	Clock rise to output data valid	-0.5 × t × (k+1) - 1.25	-0.5 × t × (k+1) + 2.25	ns
WE17	Clock rise to output data invalid	0.5 × t × (k+1) - 1.25	0.5 × t × (k+1) + 2.25	ns
WE18	Input data setup time to clock rise	2.3	—	ns
WE19	Input data hold time from clock rise	2	—	ns
WE20	EIM_WAIT_B setup time to clock rise	2	—	ns
WE21	EIM_WAIT_B hold time from clock rise	2	—	ns

1 k represents register setting BCD value.

2 t is clock period (1/Freq). For 104 MHz, t = 9.165 ns.

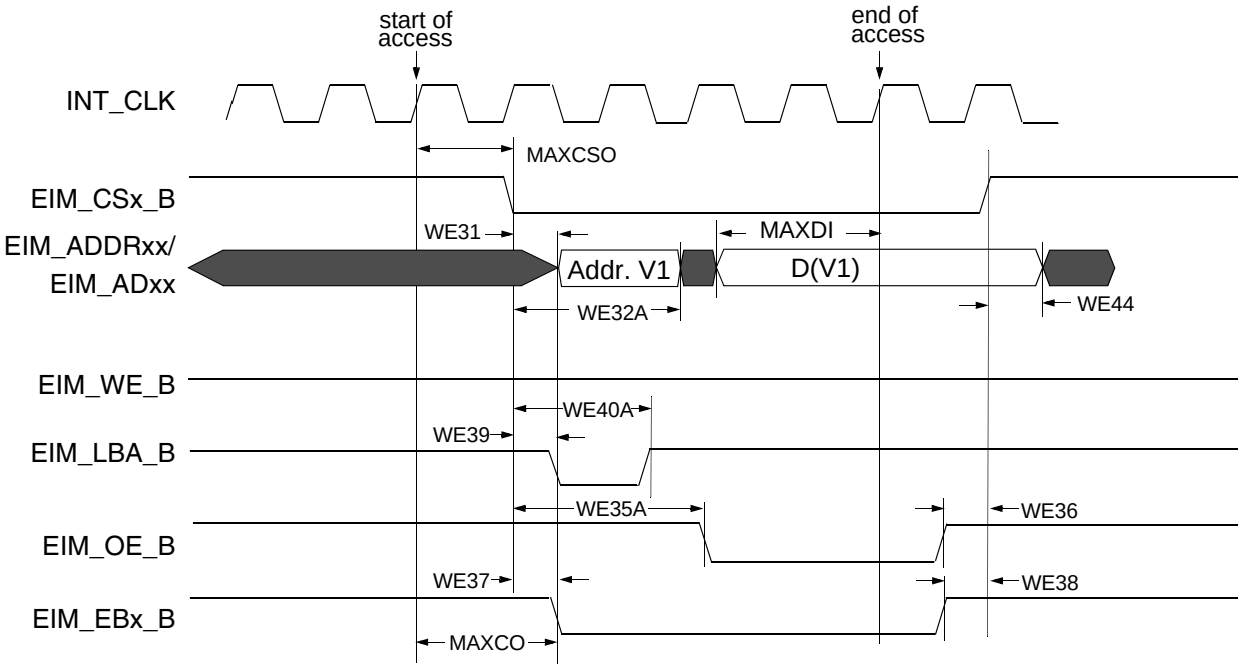

Figure 19. Asynchronous A/D Muxed Read Access (RWSC = 5)

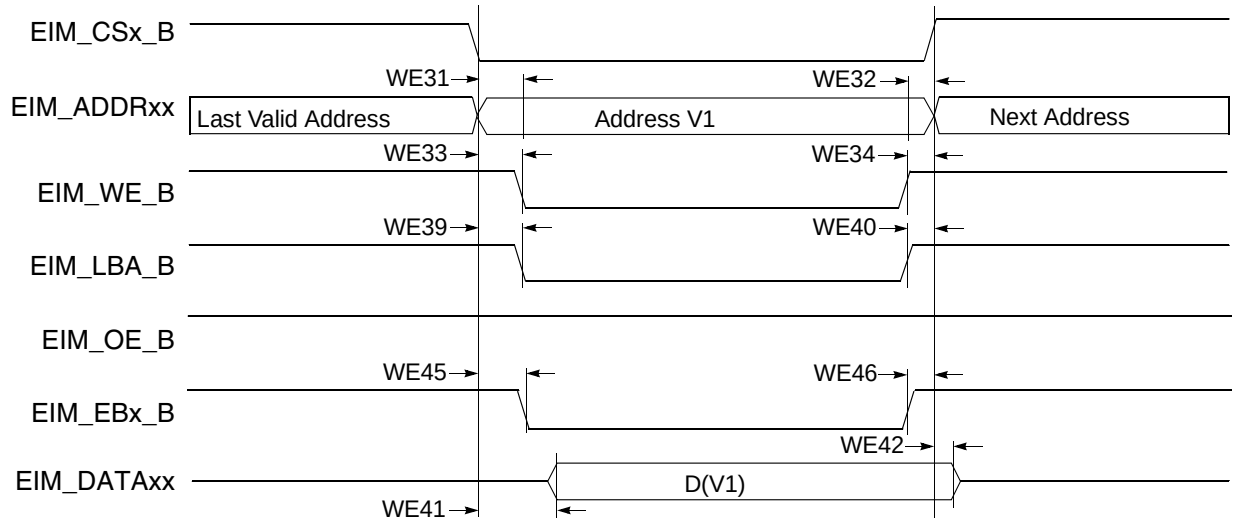

Figure 20. Asynchronous Memory Write Access

Table 46. LPDDR2 Write Cycle (continued)

ID	Parameter[1,2,3]	Symbol	CK = 400 MHz		Unit
			Min	Max	
LP22	DRAM_SDQSx_P high level width	t_{DQSH}	0.4	—	tCK
LP23	DRAM_SDQSx_P low level width	t_{DQSL}	0.4	—	tCK

1 To receive the reported setup and hold values, the write calibration must be performed to locate the DRAM_SDQSx_P in the middle of DRAM_DATAxx window.

2 All measurements are in reference to Vref level.

3 Measurements were completed using balanced load and a 25 Ω resistor from outputs to DRAM_VREF.

Figure 29 shows the LPDDR2 read timing diagram. The timing parameters for this diagram appear in Table 47.

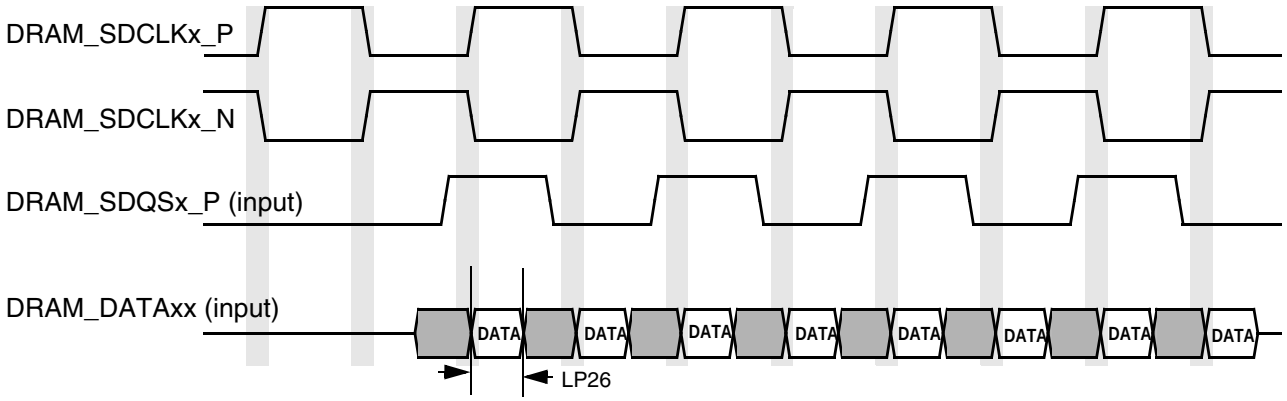

Figure 29. LPDDR2 Read Cycle

Table 47. LPDDR2 Read Cycle

ID	Parameter[1,2,3]	Symbol	CK = 400 MHz		Unit
			Min	Max	
LP26	Minimum required DRAM_DATAxx valid window width for LPDDR2	—	330	—	ps

1 To receive the reported setup and hold values, read calibration must be performed to locate the DRAM_SDQSx_P in the middle of DRAM_DATAxx window.

2 All measurements are in reference to Vref level.

3 Measurements were completed using balanced load and a 25 Ω resistor from outputs to DRAM_VREF.

4.10 General-Purpose Media Interface (GPMI) Timing

The i.MX 6DualPlus/6QuadPlus GPMI controller is a flexible interface NAND Flash controller with 8-bit data width, up to 200 MB/s I/O speed and individual chip select. It supports Asynchronous timing mode, Source Synchronous timing mode, and Samsung Toggle timing mode separately described in the following subsections.

Table 50. Samsung Toggle Mode Timing Parameters[1] (continued)

ID	Parameter	Symbol	Timing T = GPMI Clock Cycle		Unit
			Min	Max	
NF28	Data write setup	tDS[6]	0.25 × tCK - 0.32	—	ns
NF29	Data write hold	tDH[6]	0.25 × tCK - 0.79	—	ns
NF30	NAND_DQS/NAND_DQ read setup skew	tDQSQ[7]	—	3.18	—
NF31	NAND_DQS/NAND_DQ read hold skew	tQHS[7]	—	3.27	—

1 The GPMI toggle mode output timing can be controlled by the module's internal registers HW_GPMI_TIMING0_ADDRESS_SETUP, HW_GPMI_TIMING0_DATA_SETUP, and HW_GPMI_TIMING0_DATA_HOLD. This AC timing depends on these registers settings. In the table, AS/DS/DH represents each of these settings.

2 AS minimum value can be 0, while DS/DH minimum value is 1.

3 T = tCK (GPMI clock period) -0.075ns (half of maximum p-p jitter).

4 CE_DELAY represents HW_GPMI_TIMING2[CE_DELAY]. NF18 is met automatically by the design. Read/Write operation is started with enough time of ALE/CLE assertion to low level.

5 PRE_DELAY+1) ≥ (AS+DS)

6 Shown in Figure 36.

7 Shown in Figure 37.

Figure 38 shows the timing diagram of NAND_DQS/NAND_DATAxx read valid window. For DDR Toggle mode, the typical value of tDQSQ is 1.4 ns (max) and 1.4 ns (max) for tQHS at 133 MB/s. GPMI will sample NAND_DATA[7:0] at both rising and falling edge of a delayed NAND_DQS signal, which is provided by an internal DPLL. The delay value of this register can be controlled by GPMI register GPMI_READ_DDR_DLL_CTRL.SLV_DLY_TARGET (see the GPMI chapter of the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM)). Generally, the typical delay value is equal to 0x7 which means 1/4 clock cycle delay expected. However, if the board delay is large enough and cannot be ignored, the delay value should be made larger to compensate the board delay.

4.11 External Peripheral Interface Parameters

The following subsections provide information on external peripheral interfaces.

4.11.1 AUDMUX Timing Parameters

The AUDMUX provides a programmable interconnect logic for voice, audio, and data routing between internal serial interfaces (SSIs) and external serial interfaces (audio and voice codecs). The AC timing of AUDMUX external pins is governed by the SSI module. For more information, see the respective SSI electrical specifications found within this document.

4.11.2 ECSPI Timing Parameters

This section describes the timing parameters of the ECSPI block. The ECSPI has separate timing parameters for master and slave modes.

Table 64. Switching Characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_F	Differential output signal fall time	20–80% RL = 50 Ω See Figure 63.	75	—	0.4 UI	ps
—	Differential signal overshoot	Referred to 2x V_{SWING}	—	—	15	%
—	Differential signal undershoot	Referred to 2x V_{SWING}	—	—	25	%
Data and Control Interface Specifications						
$t_{Power\text{-}up}$[2]	HDMI 3D Tx PHY power-up time	From power-down to HSI_TX_READY assertion	—	—	3.35	ms

1 Relative to ideal recovery clock, as specified in the HDMI specification, version 1.4a, section 4.2.3.

2 For information about latencies and associated timings, see Section 4.11.7.1, "Latencies and Timing Information."

4.11.9 I²C Module Timing Parameters

This section describes the timing parameters of the I²C module. Figure 64 depicts the timing of I²C module, and Table 65 lists the I²C module timing characteristics.

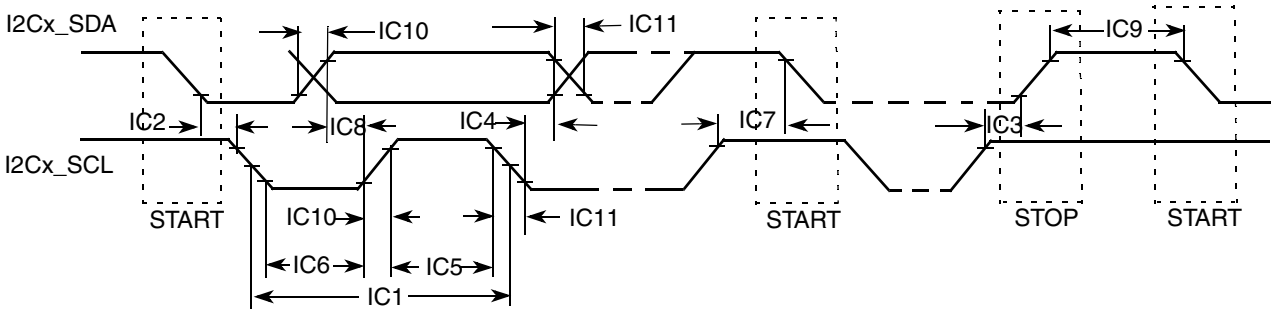

Figure 64. I²C Bus Timing

Table 65. I²C Module Timing Parameters

ID	Parameter	Standard Mode		Fast Mode		Unit
		Min	Max	Min	Max	
IC1	I2Cx_SCL cycle time	10	—	2.5	—	µs
IC2	Hold time (repeated) START condition	4.0	—	0.6	—	µs
IC3	Set-up time for STOP condition	4.0	—	0.6	—	µs
IC4	Data hold time	0[1]	3.45[2]	0[1]	0.9[2]	µs
IC5	HIGH Period of I2Cx_SCL Clock	4.0	—	0.6	—	µs
IC6	LOW Period of the I2Cx_SCL Clock	4.7	—	1.3	—	µs
IC7	Set-up time for a repeated START condition	4.7	—	0.6	—	µs
IC8	Data set-up time	250	—	100[3]	—	ns

There are special physical outputs to provide synchronous controls:

- The ipp_disp_clk is a dedicated base synchronous signal that is used to generate a base display (component, pixel) clock for a display.
- The ipp_pin_1– ipp_pin_7 are general purpose synchronous pins, that can be used to provide HSYNC, VSYNC, DRDY or any else independent signal to a display.

The IPU has a system of internal binding counters for internal events (such as, HSYNC/VSYNC) calculation. The internal event (local start point) is synchronized with internal DI_CLK. A suitable control starts from the local start point with predefined UP and DOWN values to calculate control's changing points with half DI_CLK resolution. A full description of the counter system can be found in the IPU chapter of the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

4.11.10.5.2 Asynchronous Controls

The asynchronous control is a data-oriented signal that changes its value with an output data according to additional internal flags coming with the data.

There are special physical outputs to provide asynchronous controls, as follows:

- The ipp_d0_cs and ipp_d1_cs pins are dedicated to provide chip select signals to two displays.
- The ipp_pin_11– ipp_pin_17 are general purpose asynchronous pins, that can be used to provide WR. RD, RS or any other data-oriented signal to display.

NOTE

The IPU has independent signal generators for asynchronous signals toggling. When a DI decides to put a new asynchronous data on the bus, a new internal start (local start point) is generated. The signal generators calculate predefined UP and DOWN values to change pins states with half DI_CLK resolution.

4.11.10.6 Synchronous Interfaces to Standard Active Matrix TFT LCD Panels

4.11.10.6.1 IPU Display Operating Signals

The IPU uses four control signals and data to operate a standard synchronous interface:

- IPP_DISP_CLK—Clock to display
- HSYNC—Horizontal synchronization
- VSYNC—Vertical synchronization
- DRDY—Active data

All synchronous display controls are generated on the base of an internally generated "local start point". The synchronous display controls can be placed on time axis with DI's offset, up and down parameters. The display access can be whole number of DI clock (Tdiclk) only. The IPP_DATA can not be moved relative to the local start point. The data bus of the synchronous interface is output direction only.

4.11.12.9 Low-Power Receiver Timing

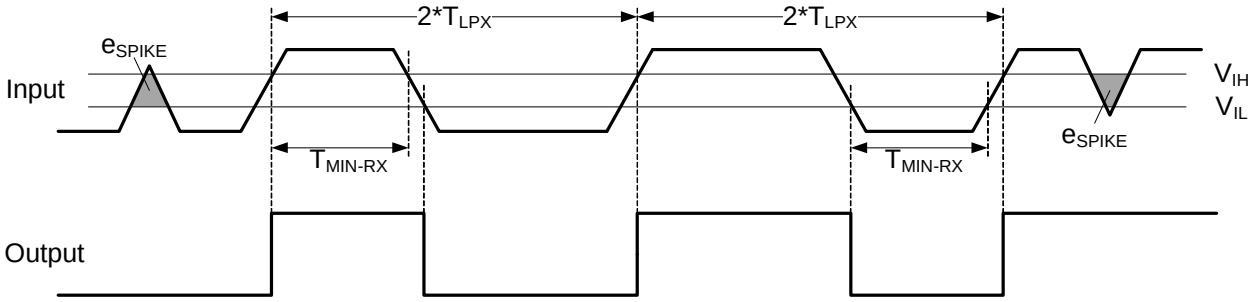

Figure 78. Input Glitch Rejection of Low-Power Receivers

4.11.13 HSI Host Controller Timing Parameters

This section describes the timing parameters of the HSI Host Controller which are compliant with High-Speed Synchronous Serial Interface (HSI) Physical Layer specification version 1.01.

4.11.13.1 Synchronous Data Flow

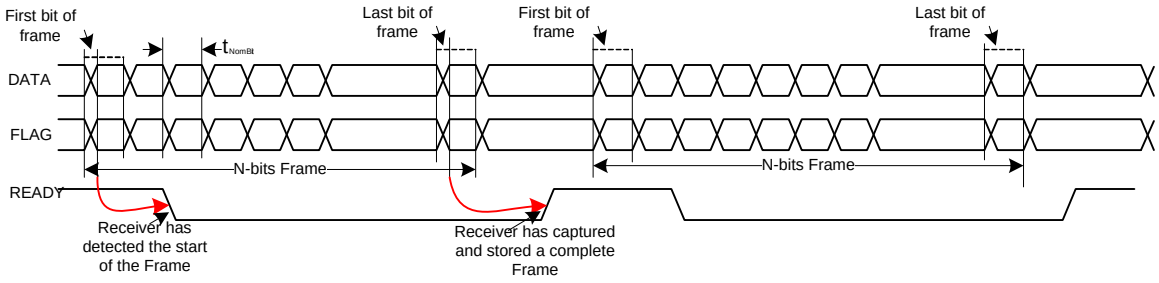

Figure 79. Synchronized Data Flow READY Signal Timing (Frame and Stream Transmission)

4.11.13.2 Pipelined Data Flow

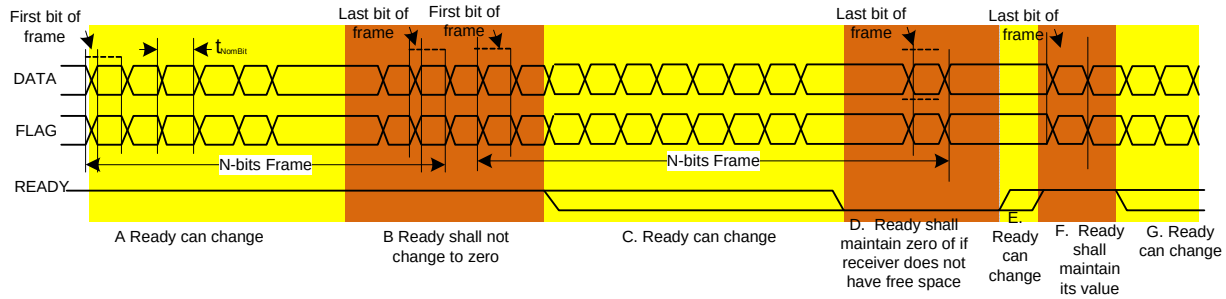

Figure 80. Pipelined Data Flow READY Signal Timing (Frame Transmission Mode)

4.11.13.3 Receiver Real-Time Data Flow

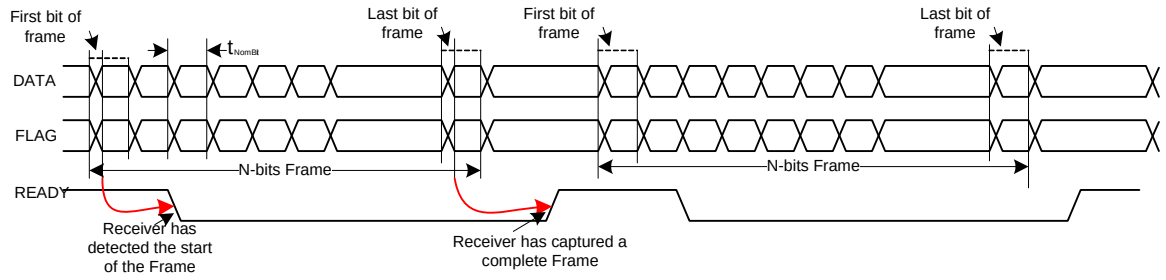

Figure 81. Receiver Real-Time Data Flow READY Signal Timing

4.11.13.4 Synchronized Data Flow Transmission with Wake

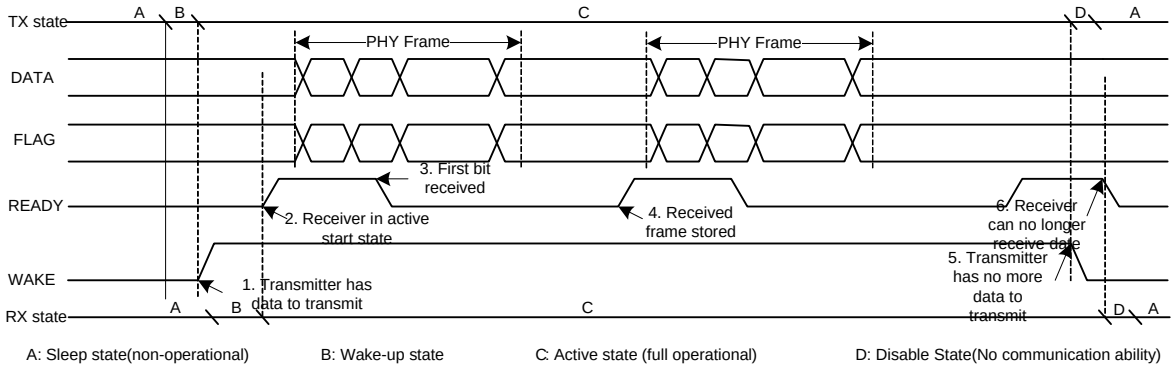

Figure 82. Synchronized Data Flow Transmission with WAKE

4.11.13.5 Stream Transmission Mode Frame Transfer

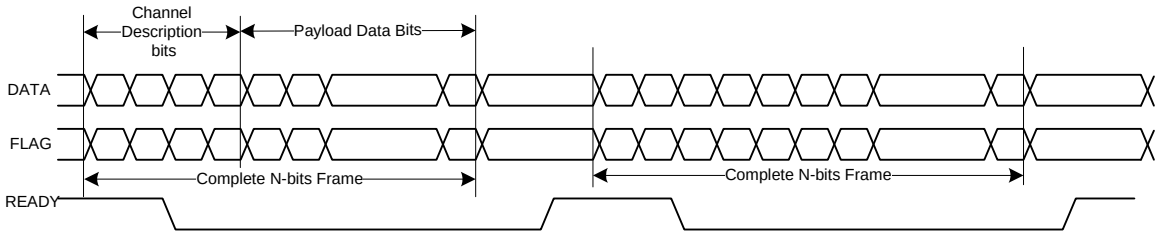

Figure 83. Stream Transmission Mode Frame Transfer (Synchronized Data Flow)

4.11.15.1 PCIE_REXT Reference Resistor Connection

The impedance calibration process requires connection of reference resistor 200 Ω. 1% precision resistor on PCIE_REXT pads to ground. It is used for termination impedance calibration.

4.11.16 Pulse Width Modulator (PWM) Timing Parameters

This section describes the electrical information of the PWM. The PWM can be programmed to select one of three clock signals as its source frequency. The selected clock signal is passed through a prescaler before being input to the counter. The output is available at the pulse-width modulator output (PWMO) external pin.

Figure 89 depicts the timing of the PWM, and Table 80 lists the PWM timing parameters.

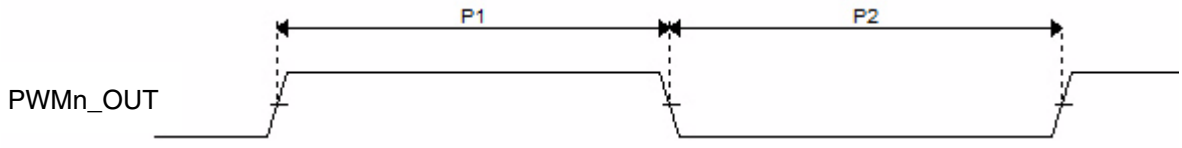

Figure 89. PWM Timing

Table 80. PWM Output Timing Parameters

ID	Parameter	Min	Max	Unit
—	PWM Module Clock Frequency	0	ipg_clk	MHz
P1	PWM output pulse width high	15	—	ns
P2	PWM output pulse width low	15	—	ns

4.11.17 SATA PHY Parameters

This section describes SATA PHY electrical specifications.

4.11.17.1 Transmitter and Receiver Characteristics

The SATA PHY meets or exceeds the electrical compliance requirements defined in the SATA specifications.

NOTE

The tables in the following sections indicate any exceptions to the SATA specification or aspects of the SATA PHY that exceed the standard, as well as provide information about parameters not defined in the standard.

The following subsections provide values obtained from a combination of simulations and silicon characterization.

Table 100. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
DISP0_DAT18	V25	NVCC_LCD	GPIO	ALT5	GPIO5_IO12	Input	PU (100K)
DISP0_DAT19	U23	NVCC_LCD	GPIO	ALT5	GPIO5_IO13	Input	PU (100K)
DISP0_DAT2	P23	NVCC_LCD	GPIO	ALT5	GPIO4_IO23	Input	PU (100K)
DISP0_DAT20	U22	NVCC_LCD	GPIO	ALT5	GPIO5_IO14	Input	PU (100K)
DISP0_DAT21	T20	NVCC_LCD	GPIO	ALT5	GPIO5_IO15	Input	PU (100K)
DISP0_DAT22	V24	NVCC_LCD	GPIO	ALT5	GPIO5_IO16	Input	PU (100K)
DISP0_DAT23	W24	NVCC_LCD	GPIO	ALT5	GPIO5_IO17	Input	PU (100K)
DISP0_DAT3	P21	NVCC_LCD	GPIO	ALT5	GPIO4_IO24	Input	PU (100K)
DISP0_DAT4	P20	NVCC_LCD	GPIO	ALT5	GPIO4_IO25	Input	PU (100K)
DISP0_DAT5	R25	NVCC_LCD	GPIO	ALT5	GPIO4_IO26	Input	PU (100K)
DISP0_DAT6	R23	NVCC_LCD	GPIO	ALT5	GPIO4_IO27	Input	PU (100K)
DISP0_DAT7	R24	NVCC_LCD	GPIO	ALT5	GPIO4_IO28	Input	PU (100K)
DISP0_DAT8	R22	NVCC_LCD	GPIO	ALT5	GPIO4_IO29	Input	PU (100K)
DISP0_DAT9	T25	NVCC_LCD	GPIO	ALT5	GPIO4_IO30	Input	PU (100K)
DRAM_A0	AC14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR00	Output	0
DRAM_A1	AB14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR01	Output	0
DRAM_A10	AA15	NVCC_DRAM	DDR	ALT0	DRAM_ADDR10	Output	0
DRAM_A11	AC12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR11	Output	0
DRAM_A12	AD12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR12	Output	0
DRAM_A13	AC17	NVCC_DRAM	DDR	ALT0	DRAM_ADDR13	Output	0
DRAM_A14	AA12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR14	Output	0
DRAM_A15	Y12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR15	Output	0
DRAM_A2	AA14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR02	Output	0
DRAM_A3	Y14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR03	Output	0
DRAM_A4	W14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR04	Output	0
DRAM_A5	AE13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR05	Output	0
DRAM_A6	AC13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR06	Output	0
DRAM_A7	Y13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR07	Output	0
DRAM_A8	AB13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR08	Output	0
DRAM_A9	AE12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR09	Output	0
DRAM_CAS	AE16	NVCC_DRAM	DDR	ALT0	DRAM_CAS_B	Output	0
DRAM_CS0	Y16	NVCC_DRAM	DDR	ALT0	DRAM_CS0_B	Output	0
DRAM_CS1	AD17	NVCC_DRAM	DDR	ALT0	DRAM_CS1_B	Output	0
DRAM_D0	AD2	NVCC_DRAM	DDR	ALT0	DRAM_DATA00	Input	PU (100K)
DRAM_D1	AE2	NVCC_DRAM	DDR	ALT0	DRAM_DATA01	Input	PU (100K)
DRAM_D10	AA6	NVCC_DRAM	DDR	ALT0	DRAM_DATA10	Input	PU (100K)

Table 100. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition[1]			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value[2]
EIM_A19	G25	NVCC_EIM1	GPIO	ALT0	EIM_ADDR19	Output	0
EIM_A20	H22	NVCC_EIM1	GPIO	ALT0	EIM_ADDR20	Output	0
EIM_A21	H23	NVCC_EIM1	GPIO	ALT0	EIM_ADDR21	Output	0
EIM_A22	F24	NVCC_EIM1	GPIO	ALT0	EIM_ADDR22	Output	0
EIM_A23	J21	NVCC_EIM1	GPIO	ALT0	EIM_ADDR23	Output	0
EIM_A24	F25	NVCC_EIM1	GPIO	ALT0	EIM_ADDR24	Output	0
EIM_A25	H19	NVCC_EIM0	GPIO	ALT0	EIM_ADDR25	Output	0
EIM_BCLK	N22	NVCC_EIM2	GPIO	ALT0	EIM_BCLK	Output	0
EIM_CS0	H24	NVCC_EIM1	GPIO	ALT0	EIM_CS0_B	Output	1
EIM_CS1	J23	NVCC_EIM1	GPIO	ALT0	EIM_CS1_B	Output	1
EIM_D16	C25	NVCC_EIM0	GPIO	ALT5	GPIO3_IO16	Input	PU (100K)
EIM_D17	F21	NVCC_EIM0	GPIO	ALT5	GPIO3_IO17	Input	PU (100K)
EIM_D18	D24	NVCC_EIM0	GPIO	ALT5	GPIO3_IO18	Input	PU (100K)
EIM_D19	G21	NVCC_EIM0	GPIO	ALT5	GPIO3_IO19	Input	PU (100K)
EIM_D20	G20	NVCC_EIM0	GPIO	ALT5	GPIO3_IO20	Input	PU (100K)
EIM_D21	H20	NVCC_EIM0	GPIO	ALT5	GPIO3_IO21	Input	PU (100K)
EIM_D22	E23	NVCC_EIM0	GPIO	ALT5	GPIO3_IO22	Input	PD (100K)
EIM_D23	D25	NVCC_EIM0	GPIO	ALT5	GPIO3_IO23	Input	PU (100K)
EIM_D24	F22	NVCC_EIM0	GPIO	ALT5	GPIO3_IO24	Input	PU (100K)
EIM_D25	G22	NVCC_EIM0	GPIO	ALT5	GPIO3_IO25	Input	PU (100K)
EIM_D26	E24	NVCC_EIM0	GPIO	ALT5	GPIO3_IO26	Input	PU (100K)
EIM_D27	E25	NVCC_EIM0	GPIO	ALT5	GPIO3_IO27	Input	PU (100K)
EIM_D28	G23	NVCC_EIM0	GPIO	ALT5	GPIO3_IO28	Input	PU (100K)
EIM_D29	J19	NVCC_EIM0	GPIO	ALT5	GPIO3_IO29	Input	PU (100K)
EIM_D30	J20	NVCC_EIM0	GPIO	ALT5	GPIO3_IO30	Input	PU (100K)
EIM_D31	H21	NVCC_EIM0	GPIO	ALT5	GPIO3_IO31	Input	PD (100K)
EIM_DA0	L20	NVCC_EIM2	GPIO	ALT0	EIM_AD00	Input	PU (100K)
EIM_DA1	J25	NVCC_EIM2	GPIO	ALT0	EIM_AD01	Input	PU (100K)
EIM_DA2	L21	NVCC_EIM2	GPIO	ALT0	EIM_AD02	Input	PU (100K)
EIM_DA3	K24	NVCC_EIM2	GPIO	ALT0	EIM_AD03	Input	PU (100K)
EIM_DA4	L22	NVCC_EIM2	GPIO	ALT0	EIM_AD04	Input	PU (100K)
EIM_DA5	L23	NVCC_EIM2	GPIO	ALT0	EIM_AD05	Input	PU (100K)
EIM_DA6	K25	NVCC_EIM2	GPIO	ALT0	EIM_AD06	Input	PU (100K)
EIM_DA7	L25	NVCC_EIM2	GPIO	ALT0	EIM_AD07	Input	PU (100K)
EIM_DA8	L24	NVCC_EIM2	GPIO	ALT0	EIM_AD08	Input	PU (100K)
EIM_DA9	M21	NVCC_EIM2	GPIO	ALT0	EIM_AD09	Input	PU (100K)

Table 101. Signals with Differing Before Reset and After Reset States (continued)

Ball Name	Before Reset State	
	Input/Output	Value
EIM_EB0	Input	PD (100K)
EIM_EB1	Input	PD (100K)
EIM_EB2	Input	PD (100K)
EIM_EB3	Input	PD (100K)
EIM_LBA	Input	PD (100K)
EIM_RW	Input	PD (100K)
EIM_WAIT	Input	PD (100K)
GPIO_17	Output	Drive state unknown (x)
GPIO_19	Output	Drive state unknown (x)
KEY_COL0	Output	Drive state unknown (x)